

Features

- Fast Switching
- Improved dv/dt Capability
- Excellent Package for Good Heat Dissipation
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance:1.5°C/W Junction to Case

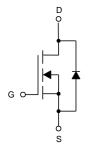
Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	V _{DS}	200	V	
Gate-Source Volltage	V _{GS}	±30	V	
Continuous Drain Current	T _C =25°C	– I _D	9	Α
	T _C =100°C		5.83	Α
Pulsed Drain Current (Note 1	I _{DM}	36	Α	
Single Pulse Avalanche Er	E _{AS}	320	mJ	
Peak Diode Recovery Ene	dV/dt	5	V/ns	
Total Power Dissipation	P _D	83	W	
Nata		1 1		1

Note:

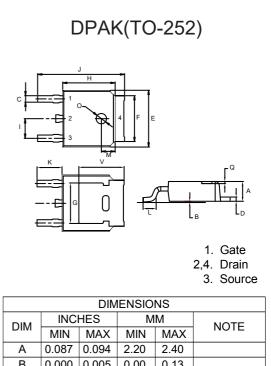
1.Pulse Width Limited by Maximum Junction Temperature. 2.L=10mH, I_{AS} =8A, V_{DD} =50V, R_{G} =25 Ω , Starting T_{J} =25°C

 $3.I_{SD} \le 9A$, di/dt $\le 200A/\mu$ s, $V_{DD} \le BV_{DSS}$, Starting T_J=25°C.

Internal Structure



N-CHANNEL MOSFET



DIM	INC	HES	N	IM	NOTE
	MIN	MAX	MIN	MAX	NOTE
А	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.1	90	4.	83	TYP.
Н	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
Κ	0.1	14	2.	90	TYP.
L	0.055	0.067	1.40	1.70	
Μ	0.0	63	1.	60	TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.2	11	5.	35	TYP.



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

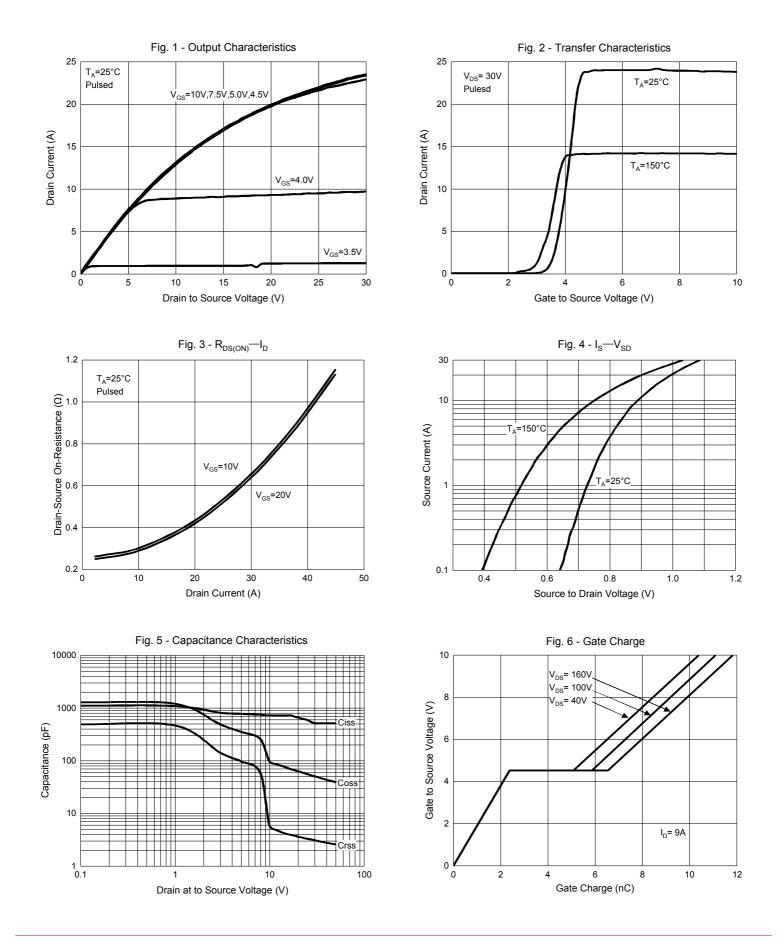
Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit
Static Characteristics				1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250µA	200			V
Breakdown Voltage Temperature Coefficient	$^{\triangle}V_{(BR)DSS}$ / $^{\triangle}T_{J}$	Reference to 25°C, I _D = 250µA		0.25		V/°C
Gate-Source Leakage Current	I _{GSS}	$V_{DS}=0V, V_{GS}=\pm 30V$			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V, V _{GS} =0V			1	μA
		V _{DS} =160V, V _{GS} =0V, T _C =125°C			10	
Gate-Threshold Voltage ^(Note 4)	V _{GS(th)}	$V_{DS}=V_{GS}, I_{D}=250\mu A$	1	1.9	3	V
Drain-Source On-Resistance ^(Note 4)	R _{DS(on)}	V _{GS} =10V, I _D =4.5A		0.21	0.25	Ω
Forward Tranconductance ^(Note 4)	g fs	V _{DS} =30V, I _D =4.5A		9.2		S
Dynamic Characteristics ^(Note 5)						
Input Capacitance	C _{iss}			509		pF
Output Capacitance	C _{oss}	V _{DS} =25V,V _{GS} =0V,f=1MHz		51.5		
Reverse Transfer Capacitance	C _{rss}			3.2		
Total Gate Charge	Qg			11.8		nC
Gate-Source Charge	Q_{gs}	V _{DD} =160V,V _{GS} =10V,I _D =9A		2.36		
Gate-Drain Charge	Q_gd			3.98		
Turn-On Delay Time	t _{d(on)}			10.33		
Turn-On Rise Time	t _r	V _{DD} =100V, I _D =9A,		10.7		- ns
Turn-Off Delay Time	t _{d(off)}	R _G =10Ω, V _{GS} =10V		29.1		
Turn-Off Fall Time	t _f			11.1		
Drain-Source Body Diode Cha	racteristics					•
Continuous Body Diode Current	I _S	- T _c =25°C			9	A
Pulsed Diode Forward Current	I _{SM}				36	
Body Diode Voltage	V_{SD}	I _S =9A, V _{GS} =0V			1.4	V
Reverse Recovery Time	t _{rr}	- V _{GS} =0V, I _F =9A,di/dt=100A/µs -		201		ns
Reverse Recovery Charge	Q _{rr}	\neg v _{GS} - ν v, i _F - ∂ A,ui/ui-i ν ∂ A/ μ S		663		nC

Note 4. Pulse Test : Pulse Width \leq 300µs, Duty Cycle \leq 2%.

5. Guaranteed by Design, Not Subject to Production Testing.



Curve Characteristics





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel	

Note : Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

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